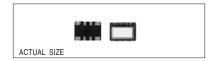


TCXO (optional Voltage Control) 3 or 3.3V, Ceramic SMD

Technical Data S6C & S7C Series





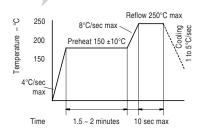
Description

A surface mountable, temperature compensated crystal oscillator with voltage control option for 3 or 3.3 Volt operation. The miniature size, extremely low profile and low power consumption of this (V)TCXO make it ideally suited for compact or portable wireless/microwave networking and telecommunications. The hermetically sealed ceramic package is fully compatible with standard surface mounting processes.

Applications & Features

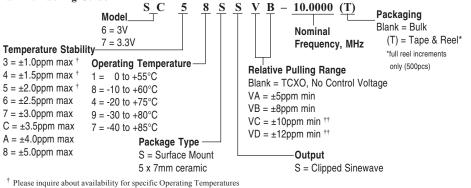
- GPS/Navigation
- Mobile and Portable Radio/Telephone
- Communications Transceivers
- · Commercial SATCOM
- Microwave transceivers
- · Wireless networking/Digital datalinks
- 3 or 3.3 Volt operation
- Analog compensation for superb phase noise and tight stabilities
- Miniature 5 x 7 mm, very low profile 2.0mm max height package
- Optional voltage control pin for frequency tuning
- Advanced lead-free design and manufacturing techniques
- Available on tape & reel; 16mm tape, 500pcs per reel

Solder Reflow Guide



Frequency Range:	10 MHz to 30 MHz
Frequency Stability:	vs. temperature: ±1ppm to ±5ppm, as specified vs. supply voltage (±5% change): ±0.3 ppm
	vs. aging: ±1ppm @40°C for one year
	vs. load: ±0.3 ppm, (CL: 10pF ±10%)
	vs. hysteresis: ± 0.2 ppm ($\delta T/\delta t = 1$ °C/min)
	vs. temp. cycles: ±0.2ppm (10 cycles min-max storage temp.)
	vs. reflow: ±1.5ppm max (room temp., nominal VC, first reflow) Perturbations: 0.3ppm peak-to-peak max
Temperature Range:	
Operating:	0 to +55°C, -20 to +75°C, -40 to +85°C, or as specified
Storage:	-40 to +85°C
Supply Voltage:	3.0V ±5% or 3.3V ±5%
Supply Current:	2mA max (3V); 2.25mA max (3.3V)
Output:	
<u>Clipped Sinewave</u> Level:	1.0V peak-to-peak min
Load:	1.0 V peak-to-peak min $10 \text{K}\Omega$ // 10pF
Pull Characteristics (if applicable): Rated Control Voltage (VC): Relative Pull Range (VC = 1.5V ±1V):	0.5V to 2.5V ±5ppm to ±12ppm (see part number guide)
Input Impedance (pin 1):	$1M\Omega$ min, $2M\Omega$ typ
Transfer Function:	Frequency increases when control voltage increases
Phase Noise:	-40 dBc/Hz @ 1Hz
(offset from carrier)	-80 dBc/Hz @ 10Hz
	-110 dBc/Hz @ 100Hz
	-135 dBc/Hz @ 1kHz -140 dBc/Hz @ 10kHz
	-140 dBc/Hz @ 10kHz -145 dBc/Hz @ 100kHz
Mechanical:	
Shock:	MIL-STD-883, Method 2002, Condition B
Solderability:	MIL-STD-883, Method 2003
Vibration:	MIL-STD-883, Method 2007, Condition A
Solvent Resistance:	MIL-STD-202, Method 215
Resistance to Soldering Heat:	MIL-STD-202, Method 210, Condition I or J
Terminal Strength:	MIL-STD-883, Method 2004, Condition D
Environmental:	MIL OTTO COS AN A LACALA CONTRACTOR
Gross Leak Test:	MIL-STD-883, Method 1014, Condition C
Fine Leak Test:	MIL-STD-883, Method 1014, Condition A2
Thermal Shock:	MIL-STD-883, Method 1011, Condition A
Moisture Resistance:	MIL-STD-883C, Method 1004

Part Numbering Guide



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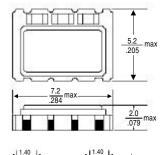
†† Please inquire about availability for specific Temperature Stabilities

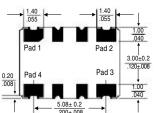


TCXO (optional Voltage Control) 3 or 3.3V, Ceramic SMD

Technical Data S6C & S7C Series

Package Details



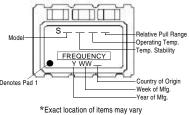


Pad Functions:

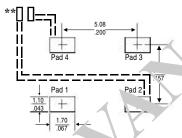
Pin 1: Control Voltage (TCXO - NC) Pin 2: GND

Pin 3: Output

Marking Format*



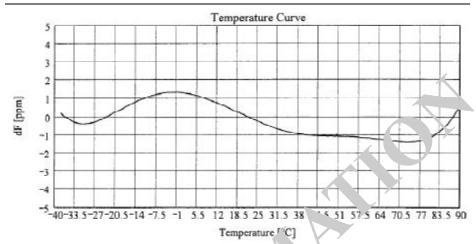
Recommended Land Pattern



**External power supply decoupin.

Scale 'one (D_i. sions in $\frac{mm}{inches}$

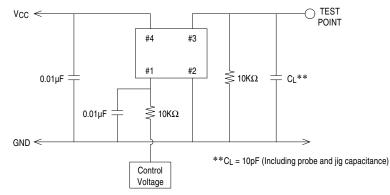
Typical Frequency vs. Temperature Characteristics



Typical Phase Noise Characteristics



st Circuit



All specifications are subject to change without notice.

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